NSN 5961-00-967-8107 Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.344 inches
Overall Diameter:
0.284 inches
Mounting Facility Quantity:
1
Mounting Method:
Threaded stud
Thread Size:
0.112 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 breakover voltage, dc
Current Rating Per Characteristic:
80.00 amperes forward current, average absolute
Power Rating Per Characteristic:
500.0 milliwatts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnpn
Thread Series Designator:
Unc
Terminal Type And Quantity:
1 threaded stud and 1 uninsulated wire lead and 1 case
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A110a0